



### **BSC059N03ST Information**

Heisener.com

Part Number BSC059N03ST

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

**Description** MOSFET N-CH 30V 50A TDSON-8

Package 8-PowerVDFN

For the pricing/inventory/lead time, please contact

us

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# **BSC059N03ST Specifications**

Manufacturer Part NumberBSC059N03STManufacturerInfineon TechnologiesCategoryDiscrete Semiconductor Products Transistors - FETs, MOSFETs - SinglePackage8-PowerVDFNSeriesOptiMOS?FET TypeN-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C19A (Ta), 89A (Tc)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2V @ 35µAGate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds2670pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)-Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN		
Category  Discrete Semiconductor Products  Transistors - FETs, MOSFETs - Single  8-PowerVDFN  Series  OptiMOS?  FET Type  N-Channel  Technology  MOSFET (Metal Oxide)  Train to Source Voltage (Vdss)  Ourrent - Continuous Drain (Id) @ 25°C  19A (Ta), 89A (Tc)  Drive Voltage (Max Rds On, Min Rds On)  Vgs(th) (Max) @ Id  Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  2670pF @ 15V  Vgs (Max)  #20V  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  Dys (Max) @ 1d, Vgs  Dys (Ti)  Mounting Type  Surface Mount  Supplier Device Package  P-TDSON-8  Package / Case	Manufacturer Part Number	BSC059N03ST
Package         8-PowerVDFN           Series         OptiMOS?           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         19A (Ta), 89A (Tc)           Drive Voltage (Max Rds On, Min Rds On)         4.5V, 10V           Vgs(th) (Max) @ Id         2V @ 35μA           Gate Charge (Qg) (Max) @ Vgs         21nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         2670pF @ 15V           Vgs (Max)         ±20V           FET Feature         -           Power Dissipation (Max)         -           Rds On (Max) @ Id, Vgs         5.5 mOhm @ 50A, 10V           Operating Temperature         -55°C ~ 150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         P-TDSON-8           Package / Case         8-PowerVDFN	Manufacturer	Infineon Technologies
Package         8-PowerVDFN           Series         OptiMOS?           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         19A (Ta), 89A (Tc)           Drive Voltage (Max Rds On, Min Rds On)         4.5V, 10V           Vgs(th) (Max) @ Id         2V @ 35µA           Gate Charge (Qg) (Max) @ Vgs         21nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         2670pF @ 15V           Vgs (Max)         ±20V           FET Feature         -           Power Dissipation (Max)         5.5 mOhm @ 50A, 10V           Operating Temperature         -55°C ~ 150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         P-TDSON-8           Package / Case         8-PowerVDFN	Category	Discrete Semiconductor Products
Series         OptiMOS?           FET Type         N-Channel           Technology         MOSFET (Metal Oxide)           Drain to Source Voltage (Vdss)         30V           Current - Continuous Drain (Id) @ 25°C         19A (Ta), 89A (Tc)           Drive Voltage (Max Rds On, Min Rds On)         4.5V, 10V           Vgs(th) (Max) @ Id         2V @ 35μA           Gate Charge (Qg) (Max) @ Vgs         21nC @ 5V           Input Capacitance (Ciss) (Max) @ Vds         2670pF @ 15V           Vgs (Max)         ±20V           FET Feature         -           Power Dissipation (Max)         -           Rds On (Max) @ Id, Vgs         5.5 mOhm @ 50A, 10V           Operating Temperature         -55°C ~ 150°C (TJ)           Mounting Type         Surface Mount           Supplier Device Package         P-TDSON-8           Package / Case         8-PowerVDFN		Transistors - FETs, MOSFETs - Single
FET TypeN-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C19A (Ta), 89A (Tc)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2V @ 35μAGate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds2670pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)-Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN	Package	8-PowerVDFN
Technology Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C 19A (Ta), 89A (Tc) Drive Voltage (Max Rds On, Min Rds On) Vgs(th) (Max) @ Id 2v @ 35µA Gate Charge (Qg) (Max) @ Vgs 1nput Capacitance (Ciss) (Max) @ Vds Vgs (Max)  FET Feature - Power Dissipation (Max) Rds On (Max) @ Id, Vgs  Operating Temperature -55°C ~ 150°C (TJ) Mounting Type Surface Mount Supplier Device Package Package / Case  MOSFET (Metal Oxide) 30V MOSFET (Metal Oxide) 30V  Edit Oxide 19A (Ta), 89A (Tc) 19A (Ta), 84 (Ta), 84 (Ta) 19A (Ta), 89A (Tc) 19A (Ta), 89A (Tc) 19A (Ta), 84 (Ta), 84 (Ta) 19A (Ta), 89A (Tc) 19A (Ta), 84 (Ta), 84 (Ta) 19A (Ta), 84 (Ta), 84 (Ta) 19A (Ta), 84 (Ta	Series	OptiMOS?
Drain to Source Voltage (Vdss)30VCurrent - Continuous Drain (Id) @ 25°C19A (Ta), 89A (Tc)Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2V @ 35μAGate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds2670pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)-Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN	FET Type	N-Channel
Current - Continuous Drain (Id) @ 25°C  Drive Voltage (Max Rds On, Min Rds On)  Vgs(th) (Max) @ Id  Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  5.5 mOhm @ 50A, 10V  Operating Temperature  Supplier Device Package  Package / Case  19A (Ta), 89A (Tc)  10A (Ta), 89A (Tc)  10A (Ta), 89A (Tc)  10A (Ta), 89A (Tc)  10A (Ta), 84 (T	Technology	MOSFET (Metal Oxide)
Drive Voltage (Max Rds On, Min Rds On)4.5V, 10VVgs(th) (Max) @ Id2V @ 35μAGate Charge (Qg) (Max) @ Vgs21nC @ 5VInput Capacitance (Ciss) (Max) @ Vds2670pF @ 15VVgs (Max)±20VFET Feature-Power Dissipation (Max)-Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN	Drain to Source Voltage (Vdss)	30V
Vgs(th) (Max) @ Id  Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  FET Feature  Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  Operating Temperature  Supplier Device Package Package / Case  2V @ 35μA  21nC @ 5V  2670pF @ 15V  2670pF	Current - Continuous Drain (Id) @ 25°C	19A (Ta), 89A (Tc)
Gate Charge (Qg) (Max) @ Vgs  Input Capacitance (Ciss) (Max) @ Vds  2670pF @ 15V  Vgs (Max)  ±20V  FET Feature  - Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  5.5 mOhm @ 50A, 10V  Operating Temperature  -55°C ~ 150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  P-TDSON-8  Package / Case  8-PowerVDFN	Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Input Capacitance (Ciss) (Max) @ Vds  Vgs (Max)  ±20V  FET Feature  - Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  5.5 mOhm @ 50A, 10V  Operating Temperature  -55°C ~ 150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  P-TDSON-8  Package / Case  8-PowerVDFN	Vgs(th) (Max) @ Id	2V @ 35μA
Vgs (Max)±20VFET Feature-Power Dissipation (Max)-Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN	Gate Charge (Qg) (Max) @ Vgs	21nC @ 5V
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Power Dissipation (Max)  Rds On (Max) @ Id, Vgs  5.5 mOhm @ 50A, 10V  Operating Temperature  -55°C ~ 150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  P-TDSON-8  Package / Case  8-PowerVDFN	Vgs (Max)	±20V
Rds On (Max) @ Id, Vgs5.5 mOhm @ 50A, 10VOperating Temperature-55°C ~ 150°C (TJ)Mounting TypeSurface MountSupplier Device PackageP-TDSON-8Package / Case8-PowerVDFN	FET Feature	-
Operating Temperature  -55°C ~ 150°C (TJ)  Mounting Type  Surface Mount  Supplier Device Package  P-TDSON-8  Package / Case  8-PowerVDFN	Power Dissipation (Max)	-
Mounting Type Surface Mount Supplier Device Package P-TDSON-8 Package / Case 8-PowerVDFN	Rds On (Max) @ Id, Vgs	5.5 mOhm @ 50A, 10V
Supplier Device Package P-TDSON-8 Package / Case 8-PowerVDFN	Operating Temperature	-55°C ~ 150°C (TJ)
Package / Case 8-PowerVDFN	Mounting Type	Surface Mount
	Supplier Device Package	P-TDSON-8
Report errors?	Package / Case	8-PowerVDFN
		Report errors?

#### **BSC059N03ST Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

# **BSC059N03ST Payment Methods**



















## **BSC059N03ST Shipping Methods**













If you have any question about BSC059N03ST, please do not hesitate to contact us!

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